

TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

# **TPCC8105**

# Lithium Ion Battery Applications Power Management Switch Applications

- · Small footprint due to a small and thin package
- Low drain-source ON-resistance:

 $RDS(ON) = 6.0 \text{ m}\Omega \text{ (typ.)} (VGS = -10 \text{ V})$ 

- Low leakage current:  $IDSS = -10 \mu A (max) (VDS = -30 V)$
- Enhancement mode:  $V_{th} = -0.8$  to -2.0 V ( $V_{DS} = -10$  V,  $I_{D} = -0.5$  mA)

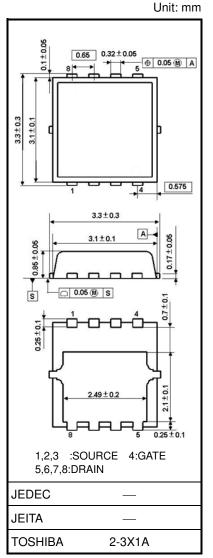
#### Absolute Maximum Ratings (Ta = 25°C)

Characte	eristic	Symbol	Rating	Unit	
Drain-source voltage		VDSS	-30	V	
Drain-gate voltage (F	$R_{GS} = 20 \text{ k}\Omega$	VDGR	-30	V	
Gate-source voltage		Vgss	-25/+20	٧	
Drain current	DC (Note 1)	ΙD	-23	Α	
Diain current	Pulsed (Note 1)	I <sub>DP</sub>	-69	^	
Drain power dissipati	on $(T_C = 25^{\circ}C)$	PD	30	W	
Drain power dissipati	on (t = 10 s)	PD	1.9	W	
	(Note 2a)		1.9	VV	
Drain power dissipati	on (t = 10 s)	PD	0.7	W	
	(Note 2b)		0.7	v V	
Single-pulse avalanc	he energy	Eas	138	mJ	
	(Note 3)	LAS	100	1110	
Avalanche current		I <sub>AR</sub>	-23	Α	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	-55 to 150	°C	

Note: For Notes 1 to 4, refer to the next page.

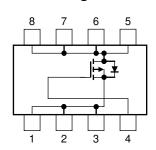
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

#### **Circuit Configuration**



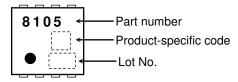
Start of commercial production 2009-11



#### **Thermal Characteristics**

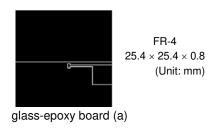
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case $(T_\text{C}=25^{\circ}\text{C})$	R <sub>th(ch-c)</sub>	4.16	°C/W
Thermal resistance, channel to ambient $(t=10 \; s) \eqno(Note \; 2a)$	Rth(ch-a)	65.7	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2b)	R <sub>th(ch-a)</sub>	178	°C/W

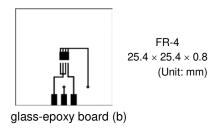
### **Marking**



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2a: Device mounted on a glass-epoxy board (a) Note 2b: Device mounted on a glass-epoxy board (b)





Note 3: VDD = -24 V, Tch = 25°C (initial), L = 200  $\mu$ H, RG = 1  $\Omega$ , IAR = -23 A



# **Electrical Characteristics (Ta = 25°C)**

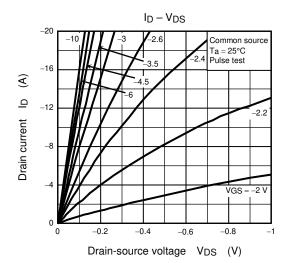
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	Igss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	ent	IDSS	V <sub>DS</sub> = -30 V, V <sub>GS</sub> = 0 V	_	_	-10	μА
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	_	V
		V(BR)DSX	I <sub>D</sub> = -10 mA, V <sub>G</sub> S = 10 V (Note 4)	-21	_	_	V
Gate threshold v	oltage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -0.5 \text{ mA}$	-0.8	_	-2.0	V
Drain aguras an	raciatanaa	_	V <sub>GS</sub> = -4 .5V, I <sub>D</sub> = -11.5 A	_	8	10.4	
Drain-source on-resistance		RDS(ON)	V <sub>GS</sub> = -10 V, I <sub>D</sub> = -11.5 A	_	6	7.8	mΩ
Input capacitanc	е	C <sub>iss</sub>		_	3240	_	
Reverse transfer capacitance		Crss	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	520	_	pF
Output capacitance		Coss		_	580	_	
Gate threshold voltage on-residence on-resid	Rise time	tr	V <sub>GS</sub> 0 V		8		- ns
	Turn-on time	ton		_	14	_	
	Fall time	tf		_	110	_	
	Turn-off time	toff	Duty $\leq$ 1%, $t_W = 10 \mu s$		330		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx -24 \text{ V}, V_{GS} = -10 \text{ V},$		76	_	
Gate-source charge 1		Q <sub>gs1</sub>	I <sub>D</sub> = -23 A	_	7.6	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>		_	20		

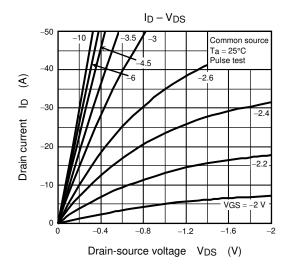
# Source-Drain Ratings and Characteristics ( $T_a = 25$ °C)

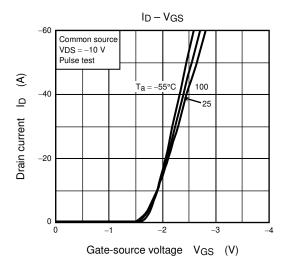
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	IDRP	_	_	_	-69	Α
Forward voltage (diode)			VDSF	IDR = -23 A, VGS = 0 V	_	_	1.2	V

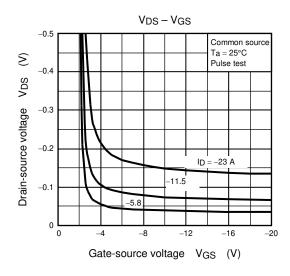
Note 4: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

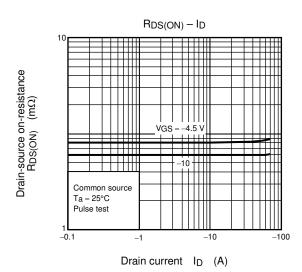




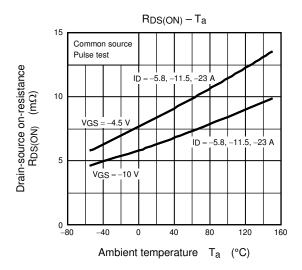


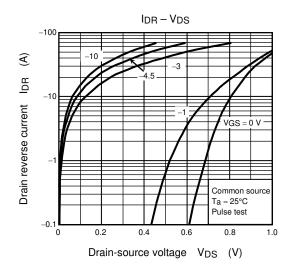


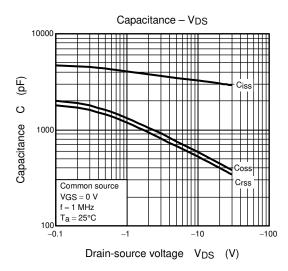


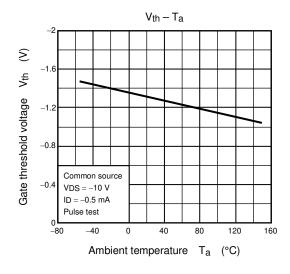


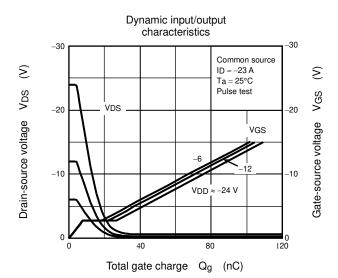




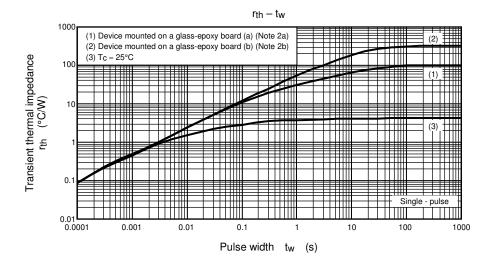


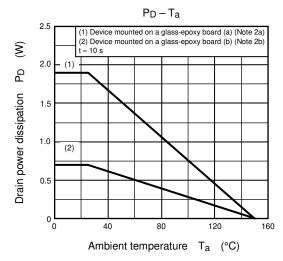


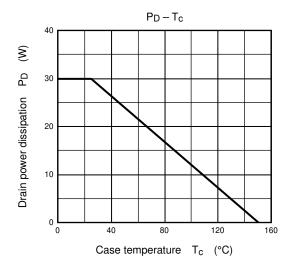


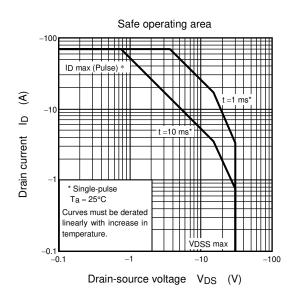














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